

Solid Tantalum Surface Mount Chip Capacitors TANTAMOUNT[™], Molded Case, Low ESR



Effective September 2005, new capacitor ratings will not be added to the 593D series. All new ratings are available in the TR3 series. The TR3 series offers state-of-the-art low ESR for switch mode power supplies and DC/DC converters.

PERFORMANCE / ELECTRICAL CHARACTERISTICS

www.vishay.com/doc?40192

Operating Temperature: -55 °C to +125 °C (above +85 °C voltage derating is required)

Capacitance Range: 0.47 μF to 680 μF

Capacitance Tolerance: ± 5 %, ± 10 %, ± 20 %

100 % Surge Current Tested (C, D and E Case Sizes)

Voltage Rating: 4 V_{DC} to 50 V_{DC}

FEATURES

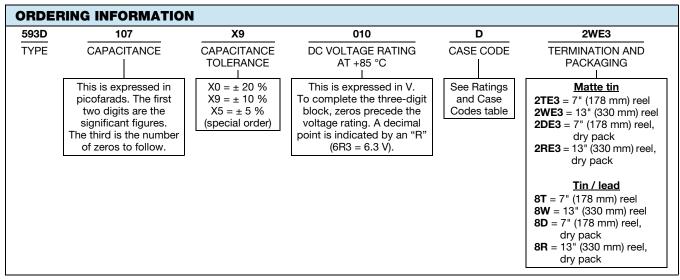
- Low ESR
- Molded case available in five case codes
- Terminations: 100 % matte tin standard, tin / lead available
- High ripple current carrying capability
- Compatible with "high volume" automatic pick and place equipment
- Qualified to EIA-717
- Moisture sensitivity level 1
- Compliant terminations
- Meets EIA-535-BAAC mechanical and performance requirements
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

APPLICATIONS

- Industrial
- Telecom infrastructure
- · General purpose



Notes

- We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size.
 Voltage substitutions will be marked with the higher voltage rating.
- Low ESR solid tantalum chip capacitors allow delta ESR of 1.25 times the datasheet limits after mounting
- Dry pack as specified in J-STD-033 for MSL3. Applicable for D and E cases only



593D

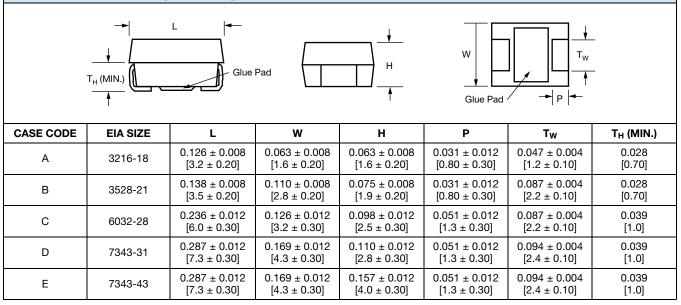
(5-2008)



593D

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DIMENSIONS in inches [millimeters]



Note

• Glue pad (non-conductive, part of molded case) is dedicated for glue attachment (as user option)

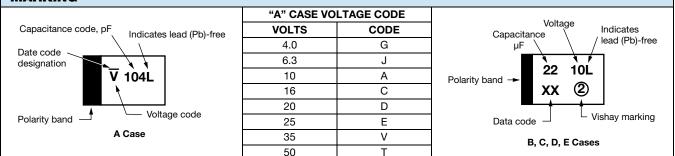
μF	4 V	6.3 V	10 V	16 V	20 V	25 V	35 V	50 V
0.47							А	
0.68							А	
1.0				А	А	А	A/B	B/C
1.5						А	B/C	B/C
2.2					А	A/B	B/C	C/D
3.3				А	А	В	С	C/D
4.7			А	A/B	A/B	B/C	С	D/E
6.8			А	A	В	С	C / D	D/E
10		А	А	A/B/C	B/C	С	C / D	D/E
15	A	А	A/B	B/C	B/C	C/D	D/E	
22	A	A/B	A/B/C	B/C	C / D	D	D/E	
33	A/B	A/B	B/C	B/C/D	C / D	D/E		
47	A/B	B/C	B/C/D	C / D	D/E	E		
68	B/C	B/C	C/D	D	D/E			
100	B / C	B/C/D	C / D	D/E	Е			
150	B/C/D	C/D/E	D/E	E				
220	C / D	D/E	D/E					
330	D	D/E	E					
470	D/E	E						
680	E							

Document Number: 40005

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<u>593</u>F

MARKING



Marking

Capacitor marking includes an anode (+) polarity band, capacitance in microfarads and the voltage rating. "A" case capacitors use a letter code for the voltage and EIA capacitance code.

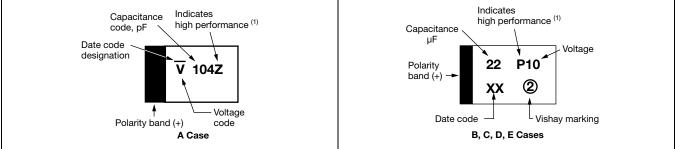
The Vishay identification marking is included if space permits. Vishay marking ("circled 2") may show additives in the form of short lines, depicting actual manufacturing facility. For A case capacitors discontinuation in polarity bar maybe used as actual manufacturing facility designation. Capacitors rated at 6.3 V are marked 6 V.

A manufacturing date code is marked on all capacitors, for details see FAQ: <u>www.vishay.com/doc?40110</u>.

Capacitors may bear TP3 marking scheme if parts are substituted with high performance automotive grade TP3 family products. This includes, for example, letter "P" as shown below.

Call the factory for further explanation.

TP3 MARKING EXAMPLE



Note

⁽¹⁾ Capital letter indicates lead (Pb)-free

STANDARD RATINGS MAX. DF MAX. ESR MAX. RIPPLE MAX. DCL CAPACITANCE AT +25 °C AT +25 °C 100 kHz CASE CODE PART NUMBER AT +25 °C 120 Hz 100 kHz (µF) I_{RMS} (µA) (%) **(**Ω) (A) 4 V_{DC} AT +85 °C; 2.7 V_{DC} AT +125 °C 593D156(1)004A(2) 0.22 15 А 0.6 6 1.500 22 А 593D226(1)004A(2) 0.9 6 1.500 0.22 593D336(1)004A(2) 1.500 0.22 33 A 1.3 6 В 33 593D336(1)004B(2) 1.3 6 0.500 0.41 47 A 593D476(1)004A(2) 1.9 14 0.800 0.31 47 В 6 0.500 0.41 593D476(1)004B(2) 1.9 68 в 593D686(1)004B(2) 2.7 6 0.500 0.41 С 68 2.7 6 0.275 0.63 593D686(1)004C(2) В 0.450 100 593D107(1)004B(2) 4.0 8 0.43 4.0 100 С 593D107(1)004C(2) 6 0.225 0.66

Note

Part number definitions:

(1) Tolerance: X0, X9. For ± 5 % tolerance (code X5) contact factory

(2) Terminations and packaging: 2TE3, 2WE3, 8T, 8W

(3) Lead (Pb)-free terminations and packaging: 2TE3, 2WE3

(4) Terminations and packaging: 2TE3, 2WE3, 8T, 8W, 2DE3, 2RE3, 8D, 8R

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STANDARD	NATINUS					
CAPACITANCE (μF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)
		4 V _{DC} AT +85 °	C; 2.7 V _{DC} AT +125	°C		
150	В	593D157(1)004B(2)	6.0	14	0.500	0.41
150	С	593D157(1)004C(2)	6.0	12	0.250	0.66
150	D	593D157(1)004D(4)	6.0	8	0.150	1.00
220	С	593D227(1)004C(2)	8.8	8	0.200	0.74
220	D	593D227(1)004D(4)	8.8	8	0.150	1.00
330	D	593D337(1)004D(4)	13.2	8	0.150	1.00
470	D	593D477(1)004D(4)	18.8	10	0.125	1.10
470	Е	593D477(1)004E(4)	18.8	10	0.100	1.28
680	Е	593D687(1)004E(4)	27.2	12	0.100	1.28
		() ()	5 °C; 4 V _{DC} AT +125	°C		
10	А	593D106(1)6R3A(2)	0.6	6	2.000	0.19
15	А	593D156(1)6R3A(2)	0.9	6	2.000	0.19
22	А	593D226(1)6R3A(2)	1.3	6	2.000	0.19
22	В	593D226(1)6R3B(2)	1.3	6	0.600	0.38
33	А	593D336(1)6R3A(2)	2.0	14	0.800	0.31
33	В	593D336(1)6R3B(2)	2.0	6	0.600	0.38
47	В	593D476(1)6R3B(2)	2.8	6	0.550	0.39
47	С	593D476(1)6R3C(2)	2.8	6	0.300	0.61
68	В	593D686(1)6R3B(2)	4.1	6	0.550	0.39
68	C	593D686(1)6R3C(2)	4.1	6	0.275	0.63
100	В	593D107(1)6R3B(2)	6.0	15	0.500	0.41
100	C	593D107(1)6R3C(2)	6.0	6	0.250	0.66
100	D	593D107(1)6R3D(4)	6.0	6	0.140	1.04
150	C	593D157(1)6R3C(2)	9.0	8	0.200	0.74
150	D	593D157(1)6R3D(4)	9.0	8	0.125	1.10
150	E	593D157(1)6R3E(4)	9.0	8	0.100	1.28
220	D	593D227(1)6R3D(4)	13.2	8	0.100	1.22
220	E	593D227(1)6R3E(4)	13.2	8	0.100	1.28
330	D	593D337(1)6R3D(4)	19.8	8	0.125	1.10
330	E	593D337(1)6R3E(4)	19.8	8	0.100	1.28
470	E	593D477(1)6R3E(4)	28.2	10	0.100	1.28
470	E	() ()	5 °C; 7 V _{DC} AT +125		0.100	1.20
4.7	A	593D475(1)010A(2)	0.5	6	3.000	0.16
6.8	A	593D685(1)010A(2)	0.7	6	3.000	0.16
10	A	593D106(1)010A(2)	1.0	6	2.000	0.19
15	A	593D156(1)010A(2)	1.5	6	2.000	0.19
15	В	593D156(1)010B(2)	1.5	6	0.700	0.35
22	A	593D226(1)010A(2)	2.2	8	1.500	0.22
22	В	593D226(1)010B(2)	2.2	6	0.700	0.22
22 33	C	593D226(1)010C(2)	2.2	6	0.345 0.600	0.56
33 33	В	593D336(1)010B(2)	3.3	6		0.38
	С	593D336(1)010C(2)	3.3	6	0.300	0.61
47	В	593D476(1)010B(2)	4.7	6	0.600	0.38
47	C	593D476(1)010C(2)	4.7	6	0.300	0.61
47	D	593D476(1)010D(4)	4.7	6	0.200	0.87
68	С	593D686(1)010C(2)	6.8	6	0.275	0.63
68	D	593D686(1)010D(4)	6.8	6	0.150	1.00

Note

Part number definitions:

(1) Tolerance: X0, X9. For \pm 5 % tolerance (code X5) contact factory

(2) Terminations and packaging: 2TE3, 2WE3, 8T, 8W
(3) Lead (Pb)-free terminations and packaging: 2TE3, 2WE3

(4) Terminations and packaging: 2TE3, 2WE3, 8T, 8W, 2DE3, 2RE3, 8D, 8R

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CAPACITANCE (µF)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μΑ)	MAX. DF AT +25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)
		10 V _{DC} AT +85	5 °C; 7 V _{DC} AT +125		<i></i> /	
100	С	593D107(1)010C(2)	10.0	8	0.200	0.74
100	D	593D107(1)010D(4)	10.0	6	0.100	1.22
150	D	593D157(1)010D(4)	15.0	8	0.100	1.22
150	Е	593D157(1)010E(4)	15.0	8	0.100	1.28
220	D	593D227(1)010D(4)	22.0	8	0.125	1.10
220	E	593D227(1)010E(4)	22.0	8	0.100	1.28
330	E	593D337(1)010E(4)	33.0	10	0.100	1.28
			°C; 10 V _{DC} AT +125	5 °C		
1.0	А	593D105(1)016A(2)	0.5	4	5.500	0.12
3.3	А	593D335(1)016A(2)	0.5	6	3.500	0.15
4.7	А	593D475(1)016A(2)	0.8	6	2.500	0.17
4.7	В	593D475(1)016B(2)	0.8	6	1.500	0.24
6.8	А	593D685(1)016A(2)	1.1	6	3.000	0.16
10	А	593D106(1)016A(2)	1.6	6	1.700	0.21
10	В	593D106(1)016B(2)	1.6	6	0.800	0.33
10	С	593D106(1)016C(2)	1.6	6	0.450	0.49
15	В	593D156(1)016B(2)	2.4	6	0.800	0.33
15	С	593D156(1)016C(2)	2.4	6	0.400	0.52
22	В	593D226(1)016B(2)	3.5	6	0.700	0.35
22	С	593D226(1)016C(2)	3.5	6	0.350	0.56
33	В	593D336(1)016B(2)	5.3	6	0.700	0.35
33	С	593D336(1)016C(2)	5.3	6	0.300	0.61
33	D	593D336(1)016D(4)	4.2	4	0.225	0.82
47	С	593D476(1)016C(2)	7.5	6	0.300	0.61
47	D	593D476(1)016D(4)	7.5	6	0.150	1.00
68	D	593D686(1)016D(4)	10.9	6	0.150	1.00
100	D	593D107(1)016D(4)	16.0	8	0.125	1.10
100	E	593D107(1)016E(4)	16.0	8	0.100	1.28
150	E	593D157(1)016E(4)	24.0	8	0.100	1.28
		20 V _{DC} AT +85	°C; 13 V _{DC} AT +125	5 °C		
1.0	А	593D105(1)020A(2)	0.5	4	5.500	0.12
2.2	А	593D225(1)020A(2)	0.5	6	4.000	0.14
3.3	А	593D335(1)020A(2)	0.7	6	4.000	0.14
4.7	А	593D475(1)020A(2)	0.9	6	3.500	0.15
4.7	В	593D475(1)020B(2)	0.9	6	1.000	0.29
6.8	В	593D685(1)020B(2)	1.4	6	1.000	0.29
10	В	593D106(1)020B(2)	2.0	6	1.000	0.29
10	С	593D106(1)020C(2)	2.0	6	0.450	0.49
15	В	593D156(1)020B(2)	3.0	6	1.000	0.29
15	С	593D156(1)020C(2)	3.0	6	0.400	0.52
22	С	593D226(1)020C(2)	4.4	6	0.375	0.54
22	D	593D226(1)020D(4)	3.5	4	0.225	0.82
33	С	593D336(1)020C(2)	6.6	6	0.350	0.56
33	D	593D336(1)020D(4)	6.6	6	0.200	0.87
47	D	593D476(1)020D(4)	9.4	6	0.200	0.87
47	E	593D476(1)020E(4)	7.5	4	0.150	1.05
68	D	593D686(1)020D(4)	13.6	6	0.175	0.93
68	E	593D686(1)020E(4)	13.6	6	0.150	1.05
100	E	593D107(1)020E(4)	20.0	8	0.150	1.05

Note ٠

Part number definitions:

(1) Tolerance: X0, X9. For ± 5 % tolerance (code X5) contact factory

(2) Terminations and packaging: 2TE3, 2WE3, 8T, 8W
(3) Lead (Pb)-free terminations and packaging: 2TE3, 2WE3

(4) Terminations and packaging: 2TE3, 2WE3, 8T, 8W, 2DE3, 2RE3, 8D, 8R

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CAPACITANCE			MAX. DCL	MAX. DF AT +25 °C	MAX. ESR AT +25 °C	MAX. RIPPLE 100 kHz
(μF)	CASE CODE	PART NUMBER	AT +25 °C (μΑ)	120 Hz (%)	100 kHz	I _{RMS}
		25 V _{P0} ΔT ±85	°C; 17 V _{DC} AT +125		(Ω)	(A)
1.0	A	593D105(1)025A(2)	0.5	4	4.000	0.14
1.5	A	593D155(1)025A(2)	0.5	6	4.000	0.14
2.2	A	593D225(1)025A(2)	0.6	6	4.000	0.14
2.2	В	593D225(1)025B(2)	0.6	6	1.500	0.14
3.3	B	593D335(1)025B(2)	0.8	6	1.500	0.24
4.7	B	593D475(1)025B(2)	1.2	6	1.500	0.24
4.7	C	593D475(1)025C(2)	1.2	6	0.525	0.24
				6		
6.8	C	593D685(1)025C(2)	1.7		0.500	0.47
10	С	593D106(1)025C(2)	2.5	6	0.450	0.49
15	С	593D156(1)025C(2)	3.8	6	0.425	0.51
15	D	593D156(1)025D(4)	3.8	6	0.250	0.77
22	D	593D226(1)025D(4)	5.5	6	0.200	0.87
33	D	593D336(1)025D(4)	8.3	6	0.200	0.87
33	E	593D336(1)025E(4)	8.3	6	0.200	0.91
47	E	593D476(1)025E(4)	11.8	6	0.200	0.91
			°C; 23 V _{DC} AT +125			
0.47	A	593D474(1)035A(2)	0.5	4	4.000	0.14
0.68	A	593D684(1)035A(2)	0.5	4	4.000	0.14
1.0	A	593D105(1)035A(2)	0.5	4	4.000	0.14
1.0	В	593D105(1)035B(2)	0.5	4	2.000	0.21
1.5	В	593D155(1)035B(2)	0.5	6	2.000	0.21
1.5	С	593D155(1)035C(2)	0.5	6	0.900	0.35
2.2	В	593D225(1)035B(2)	0.8	6	2.000	0.21
2.2	С	593D225(1)035C(2)	0.8	6	0.900	0.40
3.3	С	593D335(1)035C(2)	1.2	6	0.700	0.45
4.7	С	593D475(1)035C(2)	1.6	6	0.500	0.47
6.8	С	593D685(1)035C(2)	2.4	6	0.475	0.48
6.8	D	593D685(1)035D(4)	2.4	6	0.300	0.71
10	С	593D106(1)035C(2)	3.5	6	0.450	0.49
10	D	593D106(1)035D(4)	3.5	6	0.300	0.71
15	D	593D156(1)035D(4)	5.3	6	0.300	0.71
15	E	593D156(1)035E(4)	5.3	6	0.300	0.74
22	D	593D226(1)035D(4)	7.7	6	0.300	0.71
22	E	593D226(1)035E(4)	7.7	6	0.275	0.77
		50 V _{DC} AT +85	°C; 33 V _{DC} AT +125	5 °C		
1.0	В	593D105(1)050B(2)	0.5	4	2.000	0.21
1.0	С	593D105(1)050C(2)	0.5	4	1.600	0.26
1.5	В	593D155(1)050B(2)	0.8	6	2.000	0.21
1.5	С	593D155(1)050C(2)	0.8	6	1.500	0.27
2.2	C	593D225(1)050C(2)	1.1	6	1.500	0.27
2.2	D	593D225(1)050D(4)	1.1	6	0.800	0.43
3.3	C	593D335(1)050C(2)	1.7	6	1.500	0.27
3.3	D	593D335(1)050D(4)	1.7	6	0.800	0.43
4.7	D	593D475(1)050D(4)	2.4	6	0.600	0.50
4.7	E	593D475(1)050E(4)	1.9	6	0.600	0.50
6.8	D	593D685(1)050D(4)	3.4	6	0.600	0.50
6.8	E	., .,	3.4			0.50
		593D685(1)050E(4)		6	0.550	
10	D	593D106(1)050D(4)	5.0	6	0.550	0.52
10	E	593D106(1)050E(4)	5.0	6	0.550	0.55

Note ٠

Part number definitions:

(1) Tolerance: X0, X9. For ± 5 % tolerance (code X5) contact factory

(2) Terminations and packaging: 2TE3, 2WE3, 8T, 8W
(3) Lead (Pb)-free terminations and packaging: 2TE3, 2WE3

(4) Terminations and packaging: 2TE3, 2WE3, 8T, 8W, 2DE3, 2RE3, 8D, 8R

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For technical questions, contact: technical-questions, contact: tantalum@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



POWER DISSIPATION	
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR
A	0.075
В	0.085
С	0.110
D	0.150
E	0.165

STANDARD PACKAGING QUANTITY						
	UNITS P	ER REEL				
CASE CODE	7" REEL	13" REEL				
A	2000	9000				
В	2000	8000				
С	500	3000				
D	500	2500				
E	400	1500				

PRODUCT INFORMATION				
Guide for Molded Tantalum Capacitors				
Pad Dimensions	www.vishay.com/doc?40074			
Packaging Dimensions				
Moisture Sensitivity (MSL)	www.vishay.com/doc?40135			
SELECTOR GUIDES				
Solid Tantalum Selector Guide	www.vishay.com/doc?49053			
Solid Tantalum Chip Capacitors	www.vishay.com/doc?40091			
FAQ				
Frequently Asked Questions	www.vishay.com/doc?40110			



Guide for Molded Tantalum Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve"metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS					
DIELECTRIC	e DIELECTRIC CONSTANT				
Air or vacuum	1.0				
Paper	2.0 to 6.0				
Plastic	2.1 to 6.0				
Mineral oil	2.2 to 2.3				
Silicone oil	2.7 to 2.8				
Quartz	3.8 to 4.4				
Glass	4.8 to 8.0				
Porcelain	5.1 to 5.9				
Mica	5.4 to 8.7				
Aluminum oxide	8.4				
Tantalum pentoxide	26				
Ceramic	12 to 400K				

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the leadframe.

Molded Chip tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost

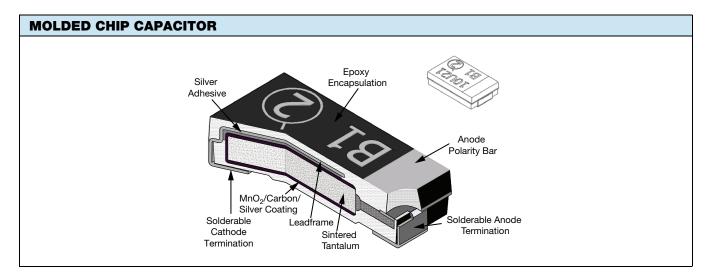
Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

CAPACITORS FOR ALL DESIGN

TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.





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COMMERCIAL PRODUCTS

SOLID TANTALUM CAPACITORS - MOLDED CASE							
SERIES	293D	793DX-CTC3- CTC4	593D	TR3	TP3	TL3	
PRODUCT IMAGE		19 18 18 18 18 18 18 18 18 18 18 18 18 18				10000 10000 10000	
TYPE		Surface mo	ount TANTAMOUNT	™, molded case			
FEATURES	Standard industrial grade	CECC approved	Low ESR	Low ESR	High performance, automotive grade	Very low DCL	
TEMPERATURE RANGE			-55 °(C to +125 °C			
CAPACITANCE RANGE	0.1 μF to 1000 μF	0.1 μF to 100 μF	1 μF to 470 μF	0.47 μF to 1000 μF	0.1 μF to 470 μF	0.1 μF to 470 μF	
VOLTAGE RANGE	4 V to 75 V	4 V to 50 V	4 V to 50 V	4 V to 75 V	4 V to 50 V	4 V to 50 V	
CAPACITANCE TOLERANCE			± 10	%, ± 20 %			
LEAKAGE CURRENT	0.005 CV or 0.25 μA, whichever is greater 0.01 CV or 0.5 μA, whichever is greater greater					0.25 µA, whichever is	
DISSIPATION FACTOR	4 % to 30 %	4 % to 6 %	4 % to 15 %	4 % to 30 %	4 % to 15 %	4 % to 15 %	
CASE CODES	A, B, C, D, E, V	A, B, C, D	A, B, C, D, E	A, B, C, D, E, V, W	A, B, C, D, E	A, B, C, D, E	
TERMINATION		10	00 % matte tin sta	andard, tin / lead availal	ole		

SOLID TANTALUM CAPACITORS - MOLDED CASE							
SERIES	ТНЗ	TH4	TH5				
PRODUCT IMAGE		1000 (B) 1000 (B) 123 (B) (B)	And				
TYPE	Sur	face mount TANTAMOUNT™, molded c	ase				
FEATURES	High temperature +150 °C, automotive grade automotive grade		Very high temperature +200 °C				
TEMPERATURE RANGE	-55 °C to +150 °C	-55 °C to +175 °C	-55 °C to +200 °C				
CAPACITANCE RANGE	0.33 μF to 220 μF	10 μF to 100 μF	4.7 μF to 100 μF				
VOLTAGE RANGE	6.3 V to 50 V	6.3 V to 35 V	5 V to 24 V				
CAPACITANCE TOLERANCE		± 10 %, ± 20 %					
LEAKAGE CURRENT	0	.01 CV or 0.5 μ A, whichever is greate	r				
DISSIPATION FACTOR	4 % to 8 %	4.5 % to 8 %	6 % to 10 %				
CASE CODES	A, B, C, D, E	B, C, D, E	D, E				
TERMINATION	100 % matte tin standard, tin / lead and gold plated available	100 % matte tin	Gold plated				



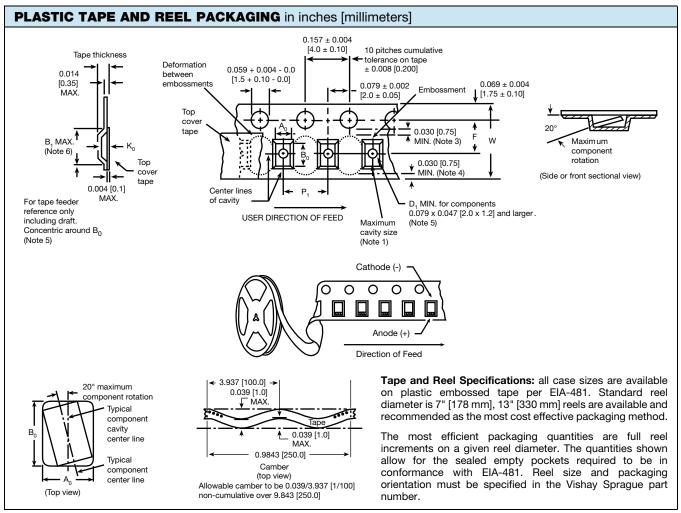
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HIGH RELIABILITY PRODUCTS

SOLID TANTALUM CAPACITORS - MOLDED CASE							
SERIES	ТМЗ	Т83	CWR11	95158			
PRODUCT IMAGE	The second secon	47715 70 3		*********			
ТҮРЕ	Tantamount™, molded case, hi-rel.	TantaMount™, molded case, hi-rel. COTS	TANTAMOUNT [™] , molded case, DLA approved				
FEATURES	High reliability, for medical Instruments	High reliability, standard and low ESR	MIL-PRF-55365/8 qualified	Low ESR			
TEMPERATURE RANGE		-55 °C to	+125 °C				
CAPACITANCE RANGE	1 μF to 220 μF	0.1 μF to 470 μF	0.1 μF to 100 μF	4.7 μF to 220 μF			
VOLTAGE RANGE	4 V to 20 V	4 V to 63 V	4 V to	50 V			
CAPACITANCE TOLERANCE	± 10 %, ± 2	20 %	± 5 %, ± 10 %, ± 20 %	± 10 %, ± 20 %			
LEAKAGE CURRENT	0.005 CV or 0.25 μA, whichever is greater	0.0	1 CV or 0.5 μA, whichever is g	greater			
DISSIPATION FACTOR	4 % to 8 %	4 % to 15 %	4 % to 6 %	4 % to 12 %			
CASE CODES	A, B, C, D, E	A, B, C, D, E	A, B, C, D	C, D, E			
TERMINATION	100 % matte tin; tin / lead	100 % matte tin; tin / lead; tin / lead solder fused	Tin / lead; tin / lead solder fused	Tin / lead solder plated; gold plated			

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Notes

- · Metric dimensions will govern. Dimensions in inches are rounded and for reference only.
- (1) A₀, B₀, K₀, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀, K₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°.
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum.
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less.
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less.
- ⁽⁵⁾ The embossed hole location shall be measured from the sprocket hole controlling the location of the embossement. Dimensions of embossement location shall be applied independent of each other.
- $^{(6)}$ B₁ dimension is a reference dimension tape feeder clearance only.

CASE CODE	TAPE SIZE	В ₁ (МАХ.)	D ₁ (MIN.)	F	К ₀ (МАХ.)	P ₁	w	
MOLDED	MOLDED CHIP CAPACITORS; ALL TYPES							
A	8 mm	0.165	0.039	0.138 ± 0.002	0.094	0.157 ± 0.004	0.315 ± 0.012	
В	0 11111	[4.2]	[1.0]	[3.5 ± 0.05]	[2.4]	$[4.0 \pm 1.0]$	$[8.0 \pm 0.30]$	
С								
D		0.00	0.050	0.017 . 0.00	0 177	0.015 . 0.004	0.470 . 0.010	
E	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.00 [5.5 ± 0.05]	0.177 [4.5]	0.315 ± 0.004 [8.0 ± 1.0]	0.472 ± 0.012 [12.0 ± 0.30]	
V		[0.2]	[1.0]	[0.0 ± 0.00]	[5]	[0.0 ± 1.0]	[12.0 ± 0.00]	
W								

Revision: 02-Aug-18

5 For technical questions, contact: <u>tantalum@vishay.com</u> Document Number: 40074

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RECOMMENDED REFLOW PRO	FILES			
Capacitors should withstand reflow profile as	per J-STD-020 standard, three cycles.			
T _p Max. ramp-up rate = 3 °C/s Max. ramp-down rate = 6 °C/s T ₁ T _s max. Preheat area T _s min. T _s				
PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY		
Preheat / soak				
Temperature min. (T _{s min.})	100 °C	150 °C		
Temperature max. (T _{s max.})	150 °C	200 °C		
Time (t _s) from (T _{s min.} to T _{s max.})	60 s to 120 s	60 s to 120 s		
Ramp-up				
Ramp-up Ramp-up rate (T _L to T _p)	3 °C/s max.	3 °C/s max.		
	3 °C/s max. 183 °C	3 °C/s max. 217 °C		
Ramp-up rate (T _L to T _p)				
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L Peak package body temperature (T_p)	183 °C 60 s to 150 s	217 °C		
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L	183 °C 60 s to 150 s	217 °C 60 s to 150 s		
Ramp-up rate (T_L to T_p) Liquidus temperature (T_L) Time (t_L) maintained above T_L Peak package body temperature (T_p) Time (t_p) within 5 °C of the specified	183 °C 60 s to 150 s Depends on case si	217 °C 60 s to 150 s ze - see table below		
$\begin{array}{l} \text{Ramp-up rate } (T_L \text{ to } T_p) \\ \text{Liquidus temperature } (T_L) \\ \text{Time } (t_L) \text{ maintained above } T_L \\ \text{Peak package body temperature } (T_p) \\ \text{Time } (t_p) \text{ within 5 } ^{\circ}\text{C} \text{ of the specified } \\ \text{classification temperature } (T_C) \end{array}$	183 °C 60 s to 150 s Depends on case si 20 s	217 °C 60 s to 150 s ze - see table below 30 s		

PEAK PACKAGE BODY TEMPERATURE (T _p)			
CASE CODE	PEAK PACKAGE BODY TEMPERATURE (Tp)		
CASE CODE	SnPb EUTECTIC PROCESS	LEAD (Pb)-FREE PROCESS	
A, B, C, V	235 °C	260 °C	
D, E, W	220 °C	250 °C	

AD DIMENSIONS	in inches [millimeters]			
$ \begin{array}{c} \bullet \\ \bullet $				
CASE CODE	A (MIN.)	B (NOM.)	C (NOM.)	D (NOM.)
IOLDED CHIP CAPACI	TORS, ALL TYPES			
А	0.071 [1.80]	0.067 [1.70]	0.053 [1.35]	0.187 [4.75]
В	0.118 [3.00]	0.071 [1.80]	0.065 [1.65]	0.207 [5.25]
С	0.118 [3.00]	0.094 [2.40]	0.118 [3.00]	0.307 [7.80]
D	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]
E	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]
V	0.157 [4.00]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]
W	0.185 [4.70]	0.098 [2.50]	0.150 [3.80]	0.346 [8.80]

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GUIDE TO APPLICATION

1. **AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

- P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).
- R_{ESR} = the capacitor equivalent series resistance at the specified frequency
- 2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{\rm RMS} = Z_{\rm V} \frac{P}{R_{\rm ESR}}$$

where,

- P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).
- R_{ESR} = the capacitor equivalent series resistance at the specified frequency
- Z = the capacitor impedance at the specified frequency
- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
- Reverse Voltage: solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at +85 °C.
- 4. **Temperature Derating:** if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

TEMPERATURE (°C)	DERATING FACTOR
+25	1.0
+85	0.9
+125	0.4
+150 (1)	0.3
+175 (1)	0.2
+200 (1)	0.1

Note

⁽¹⁾Applicable for dedicated high temperature product series

5. **Power Dissipation:** power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I_{BMS} value

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be established when calculating permissible operating levels. (Power dissipation calculated using +25 °C temperature rise).

6. **Printed Circuit Board Materials:** molded capacitors are compatible with commonly used printed circuit board materials (alumina substrates, FR4, FR5, G10, PTFE-fluorocarbon and porcelanized steel).

7. Attachment:

- 7.1 **Solder Paste:** the recommended thickness of the solder paste after application is $0.007" \pm 0.001"$ [0.178 mm ± 0.025 mm]. Care should be exercised in selecting the solder paste. The metal purity should be as high as practical. The flux (in the paste) must be active enough to remove the oxides formed on the metallization prior to the exposure to soldering heat. In practice this can be aided by extending the solder preheat time at temperatures below the liquidous state of the solder.
- 7.2 **Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 2 °C per s. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor.
- 7.2.1 **Backward and Forward Compatibility:** capacitors with SnPb or 100 % tin termination finishes can be soldered using SnPb or lead (Pb)-free soldering processes.
- 8. Cleaning (Flux Removal) After Soldering: molded capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.
- 8.1 When using ultrasonic cleaning, the board may resonate if the output power is too high. This vibration can cause cracking or a decrease in the adherence of the termination. DO NOT EXCEED 9W/I at 40 kHz for 2 min.
- 9. Recommended Mounting Pad Geometries: proper mounting pad geometries are essential for successful solder connections. These dimensions are highly process sensitive and should be designed to minimize component rework due to unacceptable solder joints. The dimensional configurations shown are the recommended pad geometries for both wave and reflow soldering techniques. These dimensions are intended to be a starting point for circuit board designers and may be fine tuned if necessary based upon the peculiarities of the soldering process and / or circuit board design.



Molded Chip Tantalum Capacitors

ITEM	PERFORMANCE CHARACTERISTICS			
Category temperature range	-55 °C to +85 °C (to +125 °C with voltage derating)			
Capacitance tolerance	± 20 %, ± 10 %. Tested via bridge method, at +25 °C, 120 Hz			
Dissipation factor	Limit per Standard Ratings table. Tested via bridge method, at 25 °C, 120 Hz			
ESR	Limit per Standard Ratings table. Tested via bridge method, at 25 °C, 100 kHz			
Leakage current	After application of rated voltage applied to capacitors for 5 min using a steady source of power with 1 k Ω resistor in series with the capacitor under test, leakage current at 25 °C is not more than 0.01 CV or 0.5 μ A, whichever is greater. Note that the leakage current varies with temperature and applied voltage. See graph below for the appropriate adjustment factor.			
Capacitance change by temperature	+20 % max. (at +125 °C) +10 % max. (at +85 °C) -10 % max. (at -55 °C)			
Reverse voltage	Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at +25 °C 5 % of the DC rating at +85 °C Vishay does not recommend intentional or repetitive application of reverse voltage			
Ripple current	For maximum ripple current values (at 25 °C) refer to relevant datasheet. If capacitors are to be used at temperatures above +25 °C, the permissible RMS ripple current (or voltage) shall be calculated using the derating factors: 1.0 at +25 °C; 0.9 at +85 °C; 0.4 at +125 °C			
Maximum operating and surge	+85 °C +125 °C		o °C	
voltages vs. temperature	RATED VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)	SURGE VOLTAGE (V)
	4	5.2	2.7	3.4
	6.3	8	4	5
	10	13	7	8
	16	20	10	12
	20	26	13	16
	25	32	17	20
	35 ⁽³⁾	46	23	28
	35 (4)	42	23	28
	50	65	33	40
	50 (1)	60	33	40
	63	75	42	50
	75 ⁽²⁾	75	50	50
Recommended voltage	VOLTAGE RAIL		CAPACITOR VOLTAGE RATING	
derating guidelines (below 85 °C)	≤ 3.3		6.3	
、	5		10	
	1	0	20	
	12		25	
	1	5	35	
	≥ 24 50 or series configur		onfiguration	

Notes

• All information presented in this document reflects typical performance characteristics

 $^{(1)}$ Capacitance values 15 μF and higher

(2) For 293D and TR3 only

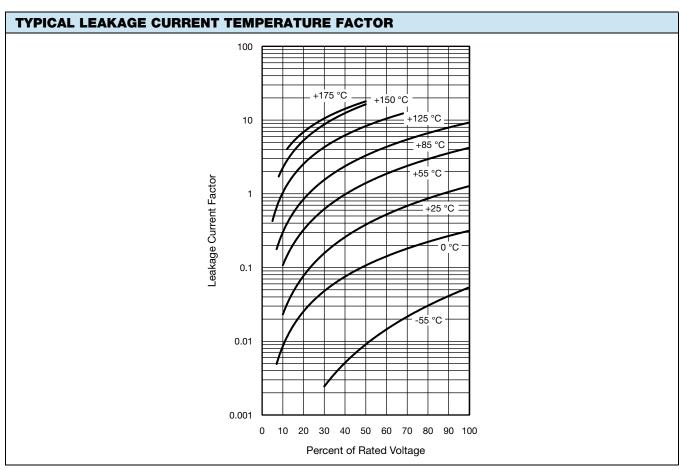
 $^{(3)}$ Capacitance values lower than 33 μF

 $^{(4)}$ Capacitance values 33 μ F and higher

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Note

At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table

At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table

At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table At +150 °C, the leakage current shall not exceed 15 times the value listed in the Standard Ratings table

At +175 °C, the leakage current shall not exceed 18 times the value listed in the Standard Ratings table

ENVIRONMENTAL PERFORMANCE CHARACTERISTICS			
ITEM	CONDITION	POST TEST PERFORMANCE	
Surge voltage	Post application of surge voltage (as specified in the table above) in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF, for 1000 successive test cycles at 85 °C.	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Initial specified limit
Life test at +85 °C	1000 h application of rated voltage at 85 °C. MIL-STD-202, method 108	Capacitance change Dissipation factor Leakage current	Within -20 % / +10 % of initial value Initial specified limit Shall not exceed 125 % of initial limit
Life test at +125 °C	1000 h application 2/3 of rated voltage at 125 °C. MIL-STD-202, method 108	Capacitance change Dissipation factor Leakage current	Within -20 % / +10 % of initial value Initial specified limit Shall not exceed 125 % of initial limit
Humidity tests	At 60 °C / 90 % RH 1000 h, biased	Capacitance change Dissipation factor Leakage current	Within -10 % / +20 % of initial value Not to exceed 150 % of initial limit Shall not exceed 200 % of initial limit
Thermal shock	MIL-STD-202, method 107, test condition A (-55 °C / +85 °C, for 1000 cycles)	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Initial specified limit



MECHANICAL PERFORMANCE CHARACTERISTICS				
TEST CONDITION	CONDITION	POST TEST PERFORMANCE		
Terminal strength / shear force test	Apply a pressure load of 17.7 N for 60 s horizontally to the center of capacitor side body.	Capacitance changeWithin ± 10 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit		
		There shall be no mechanical or visual damage to capacitors post-conditioning.		
Vibration	MIL-STD-202, method 204, condition D, 10 Hz to 2000 Hz, 20 <i>g</i> peak, 8 h, at rated voltage	Electrical measurements are not applicable, since the same parts are used for shock (specified pulse) test. There shall be no mechanical or visual damage to capacitors post-conditioning.		
Shock (specified pulse)	MIL-STD-202, method 213, condition I, 100 <i>g</i> peak	Capacitance changeWithin ± 10 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit		
		There shall be no mechanical or visual damage to capacitors post-conditioning.		
Resistance to soldering heat	Recommended reflow profiles temperatures and durations are located within the Capacitor Series Guides	Capacitance changeWithin ± 10 % of initial valueDissipation factorInitial specified limitLeakage currentInitial specified limit		
MIL-STD-202, method 210, condition B		There shall be no mechanical or visual damage to capacitors post-conditioning.		
Solderability and dissolution of metallization	MIL-STD-202, method 208, ANSI/J-STD-002, test B (SnPb) and B1 (lead (Pb)-free). Dissolution of metallization: method D. Does not apply to gold terminations.	There shall be no mechanical or visual damage to capacitors post-conditioning.		
Flammability	Encapsulation materials meet UL 94 V-0 with an oxygen index of 32 %.			



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